PNJ4812M (Tentative)

Photodiode with amplifier functions

For infrared remote control systems

Features

- \bullet Center frequency f_{O} : 38.0 kHz
- Operating supply voltage V_{CC} : 3.3 V (typ.)
- Adoption of visible light cutoff resin

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Operating supply voltage	V _{CC}	-0.5 to +6	V	
Power dissipation	P _D	200	mW	
Operating ambient temperature	T _{opr}	-20 to +70	°C	
Storage temperature	T _{stg}	-40 to +100	°C	
Soldering temperature *	T _{sol}	260	°C	

Note) *: Less than 5 s

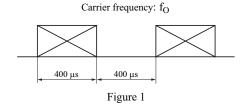
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$, $V_{CC} = 3.3 V$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Operating supply voltage	V _{CC}		2.7	3.3	5.5	V
Output voltage low-level *2	V _{OL}	$L \le 11.0 \text{ m}, I_{OL} = 400 \ \mu\text{A}$		0.1	0.3	V
Output voltage high-level	V _{OH}	No signal condition	V _{CC} - 0.2	V _{CC}	V _{CC}	V
Supply current	I _{CC}	No signal condition		0.3	0.45	mA
Maximum reception distance *1	L _{max}		11.0		_	m
45 ° detection distance *1	L45	Incident angle of the signal = 45 $^{\circ}$	5.0		_	m
Pulse width low-level *1	t _{WL}	$L \le 0.1$ m to 11.0 m, 16 pulse	200	400	600	μs
Pulse width high-level *1	t _{WH}	$L \le 0.1 \text{ m to } 11.0 \text{ m}, 16 \text{ pulse}$	200	400	600	μs
Center frequency	f _O			38.0	_	kHz

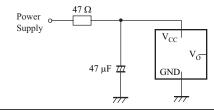
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. *1: Burst wave form Figure 1

*2: Burst wave form Figure 2



3. Measurement circuit



Carrier frequency: fo

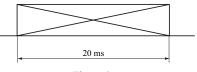
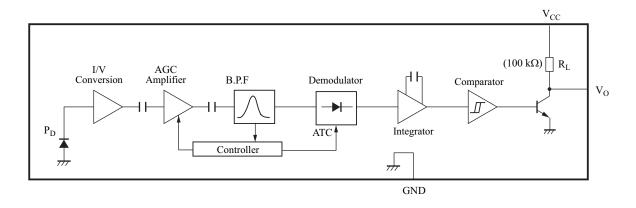
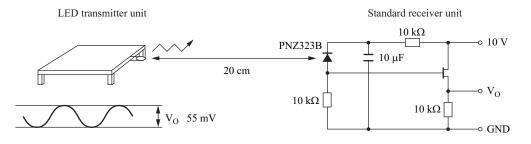


Figure 2

Block Diagram



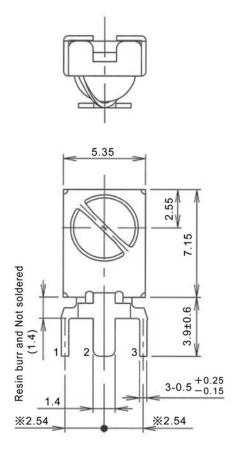
Panasonic Transmitter Specifications

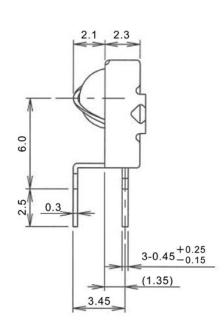


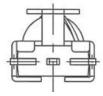
- 1. The output of the LED transmitter unit is adjusted so that the output standard receiver unit, V_0 may be 55 mV when transmitting waves (duty = 50%) are output from the transmitter unit, where the sensitivity to infrared emitters (SIR) of PNZ323B is 0.53 μ A when the irradiance H is 12.45 μ W/cm².
- 2. The maximum detection distance of this specification is guaranteed by t_{WH} and t_{WL} being within the limits when constant 16 pulses are transmitted with the output of the transmitter unit corresponded to the maximum detection distance in the system above. (The maximum detection distance is measured in the darkness without disturbing noises.)

Package (Unit: mm)

LPTLSN3S0002







- Pin name
 - 1. V_O
 - 2. GND
 - $3. V_{CC}$

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